TOSHIBA Transistor Silicon PNP Epitaxial Type

2SA2060

High-Speed Switching Applications DC-DC Converter Applications Strobe Applications

- High DC current gain: $h_{FE} = 200$ to 500 (IC = -0.5 A)
- Low collector-emitter saturation voltage: V_{CE} (sat) = -0.2 V (max)
- High-speed switching: tf = 90 ns (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	-50	V	
Collector-emitter voltage		V _{CEO}	-50	V	
Emitter-base voltage		V _{EBO}	-7	V	
Collector current	DC	Ι _C	-2.0	А	
	Pulse	I _{CP}	-3.5		
Base current		Ι _Β	-200	mA	
Collector power dissipation	t = 10 s	P _C	2.5	W	
	DC	(Note 1)	1.0		
Junction temperature		Тj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.05 g (typ.)

Note 1: Mounted on an FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm^2)

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current		I _{CBO}	$V_{CB} = -50 \text{ V}, \text{ I}_{E} = 0$	-	_	-100	nA	
Emitter cut-off current		I _{EBO}	V _{EB} = -7 V, I _C = 0	_	_	-100	nA	
Collector-emitter breakdown voltage		V (BR) CEO	I _C = −10 mA, I _B = 0	-50	_	_	V	
DC current gain		h _{FE} (1)	V _{CE} = -2 V, I _C = -0.3 A	200	—	500		
		h _{FE} (2)	V _{CE} = -2 V, I _C = -1.0 A	100	_	_		
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = -1.0 A, I _B = -0.033 A	_	_	-0.2	V	
Base-emitter saturation voltage		V _{BE (sat)}	I _C = -1.0 A, I _B = -0.033 A	_	_	-1.1	V	
Collector output capacitance		C _{ob}	V _{CB} = -10 V, I _E = 0, f = 1 MHz	_	20	_	pF	
Switching time	Rise time	t _r	See Figure 1 circuit diagram.	_	60	_	ns	
	Storage time	t _{stg}	V _{CC} ≈ −30 V, R _L = 30 Ω	_	250	—		
	Fall time	t _f	−I _{B1} = I _{B2} = −33 mA	_	90	—		

Unit: mm

Marking





Figure 1 Switching Time Test Circuit & Timing Chart

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